

MITSUBISHI IGBT MODULES
CM150TU-12H

HIGH POWER SWITCHING USE
 INSULATED TYPE

CM150TU-12H



- Ic 150A
- VCES 600V
- Insulated Type
- 6-elements in a pack
- UL Recognized

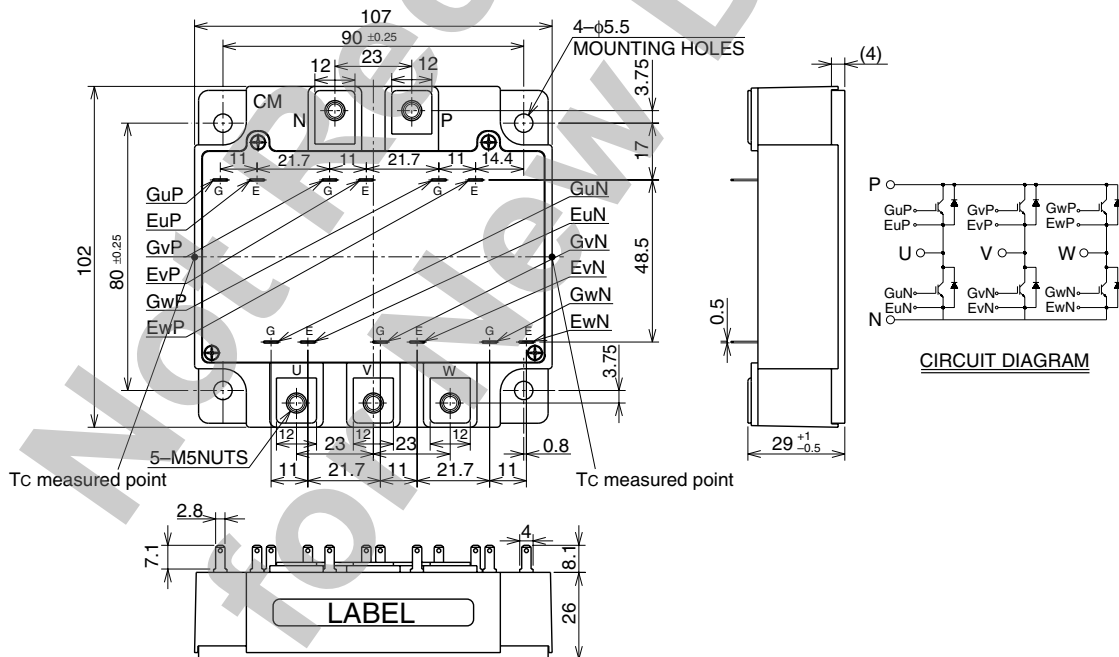
Yellow Card No. E80276
 File No. E80271

APPLICATION

UPS, NC machine, AC-Drive control, Servo, Welders

OUTLINE DRAWING & CIRCUIT DIAGRAM

Dimensions in mm



CM150TU-12H

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INSULATED TYPEMAXIMUM RATINGS ($T_j = 25^\circ\text{C}$, unless otherwise specified)

Symbol	Item	Conditions	Ratings	Unit
V _{CES}	Collector-emitter voltage	V _{GE} = 0V	600	V
V _{GES}	Gate-emitter voltage	V _{CE} = 0V	±20	V
I _C	Collector current	T _C = 25°C	150	A
I _{CM}		Pulse (Note 1)	300	A
I _E (Note 2)	Emitter current	T _C = 25°C	150	A
I _{EM} (Note 2)		Pulse (Note 1)	300	A
P _C (Note 3)	Maximum collector dissipation	T _C = 25°C	600	W
T _j	Junction temperature	—	-40 ~ +150	°C
T _{stg}	Storage temperature	—	-40 ~ +125	°C
V _{iso}	Isolation voltage	Charged part to base plate, f = 60Hz, AC 1 minute	2500	V _{rms}
—	Mounting torque	Main terminals M5 screw	2.5 ~ 3.5	N·m
—		Mounting M5 screw	2.5 ~ 3.5	N·m
—	Weight	Typical value	680	g

ELECTRICAL CHARACTERISTICS ($T_j = 25^\circ\text{C}$, unless otherwise specified)

Symbol	Item	Test Conditions	Limits			Unit
			Min	Typ	Max	
I _{CES}	Collector cutoff current	V _{CE} = V _{CES} , V _{GE} = 0V	—	—	1	mA
V _{GE(th)}	Gate-emitter threshold voltage	I _C = 15mA, V _{CE} = 10V	4.5	6	7.5	V
I _{GES}	Gate-leakage current	±V _{GE} = V _{GES} , V _{CE} = 0V	—	—	0.5	μA
V _{CE(sat)}	Collector-emitter saturation voltage	I _C = 150A, V _{GE} = 15V (Note 4)	—	2.4	3.0	V
		T _j = 25°C T _j = 125°C	—	2.6	—	
C _{ies}	Input capacitance	V _{CE} = 10V	—	—	13.2	nF
C _{oes}	Output capacitance	V _{GE} = 0V	—	—	7.2	nF
C _{res}	Reverse transfer capacitance	—	—	—	2	nF
Q _G	Total gate charge	V _{CC} = 300V, I _C = 150A, V _{GE} = 15V	—	300	—	nC
t _{d(on)}	Turn-on delay time	V _{CC} = 300V, I _C = 150A	—	—	100	ns
t _r	Turn-on rise time	V _{GE} = ±15V	—	—	350	ns
t _{d(off)}	Turn-off delay time	R _G = 4.2Ω	—	—	300	ns
t _f	Turn-off fall time	Resistive load	—	—	300	ns
V _{EC} (Note 2)	Emitter-collector voltage	I _E = 150A, V _{GE} = 0V	—	—	2.6	V
t _{rr} (Note 2)	Reverse recovery time	I _E = 150A,	—	—	160	ns
Q _{rr} (Note 2)	Reverse recovery charge	die / dt = -300A / μs	—	0.36	—	μC
R _{th(j-c)Q}	Thermal resistance (Note 5)	Junction to case, IGBT part (Per 1/6 module)	—	—	0.21	K/W
R _{th(j-c)R}		Junction to case, FWDi part (Per 1/6 module)	—	—	0.47	K/W
R _{th(c-f)}	Contact thermal resistance	Case to heat sink, conductive grease applied (Per 1/6 module) (Note 6)	—	0.09	—	K/W

Note 1. Pulse width and repetition rate should be such that the device junction temperature (T_j) does not exceed T_{jmax} rating.

2. I_E, V_{EC}, t_{rr}, Q_{rr} & die/dt represent characteristics of the anti-parallel, emitter-collector free-wheel diode.

3. Junction temperature (T_j) should not increase beyond 150°C.

4. Pulse width and repetition rate should be such as to cause negligible temperature rise.

5. Case temperature (T_c) measured point is shown in page OUTLINE DRAWING.

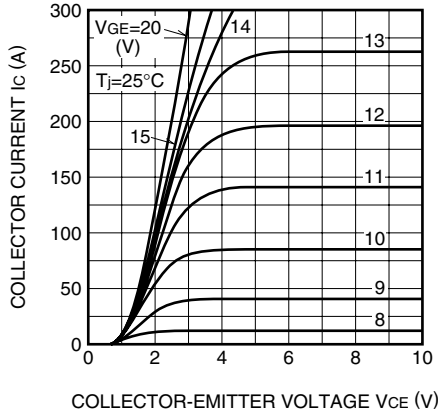
6. Typical value is measured by using thermally conductive grease of $\lambda = 0.9[\text{W}/(\text{m} \cdot \text{K})]$.

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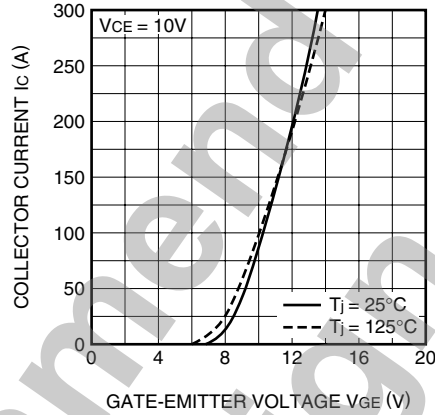
HIGH POWER SWITCHING USE
INSULATED TYPE

PERFORMANCE CURVES

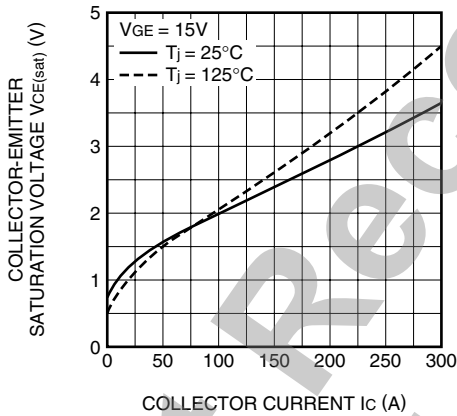
OUTPUT CHARACTERISTICS (TYPICAL)



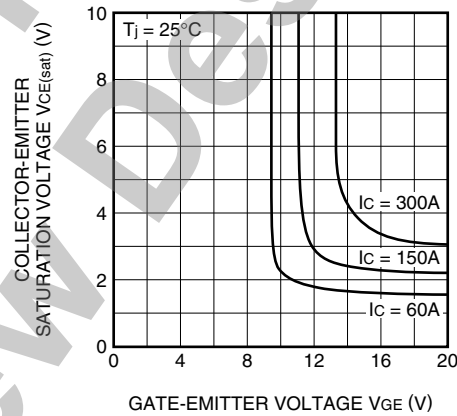
TRANSFER CHARACTERISTICS (TYPICAL)



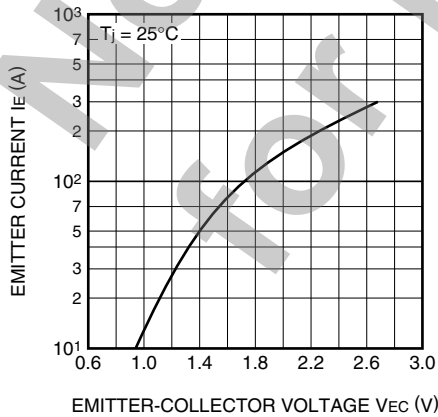
COLLECTOR-EMITTER SATURATION VOLTAGE CHARACTERISTICS (TYPICAL)



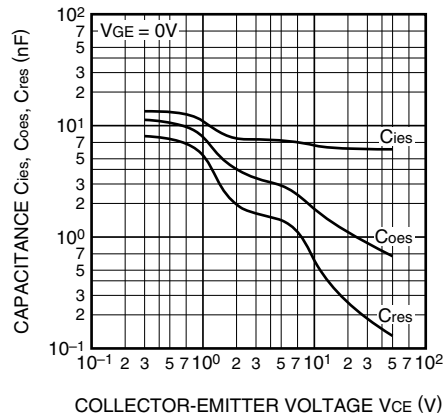
COLLECTOR-EMITTER SATURATION VOLTAGE CHARACTERISTICS (TYPICAL)



FREE-WHEEL DIODE FORWARD CHARACTERISTICS (TYPICAL)



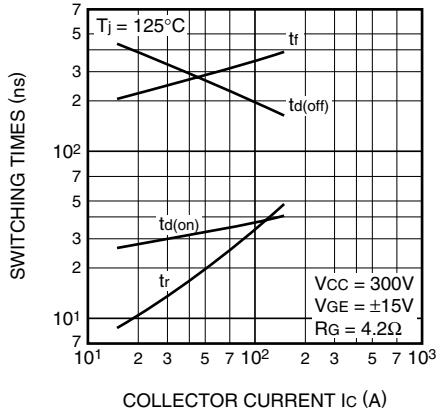
CAPACITANCE CHARACTERISTICS (TYPICAL)



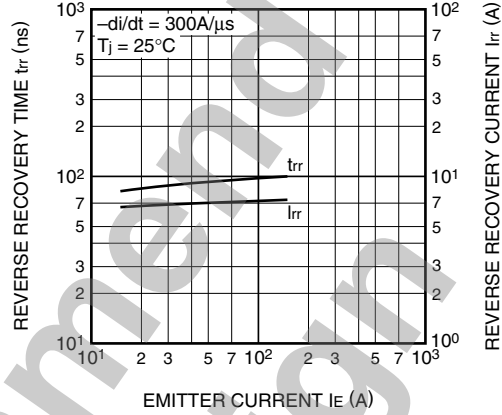
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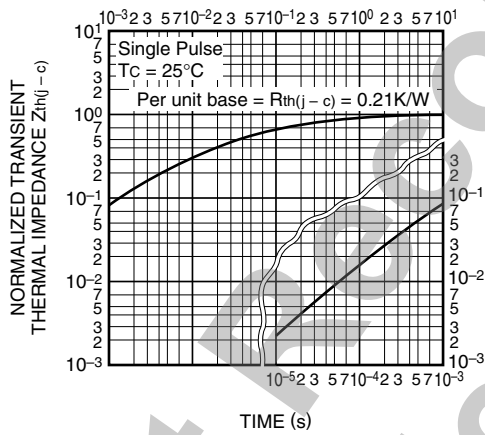
HALF-BRIDGE SWITCHING TIME CHARACTERISTICS (TYPICAL)



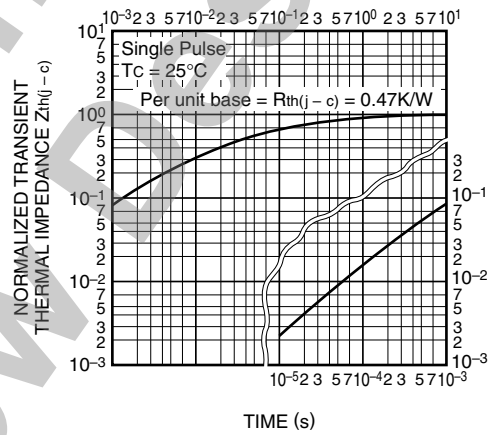
REVERSE RECOVERY CHARACTERISTICS OF FREE-WHEEL DIODE (TYPICAL)



TRANSIENT THERMAL IMPEDANCE CHARACTERISTICS (IGBT part)



TRANSIENT THERMAL IMPEDANCE CHARACTERISTICS (FWDi part)



GATE CHARGE CHARACTERISTICS (TYPICAL)

